



DMN2028UFDF

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
	$25m\Omega @ V_{GS} = 4.5V$	7.9A
20V	29mΩ @ V_{GS} = 2.5V	7.2A
	39mΩ @ V _{GS} = 1.8V	6.1A
	95mΩ @ V _{GS} = 1.5V	4.0A

Description

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- **Battery Management Application**
- **Power Management Functions**
- **DC-DC Converters**

Features

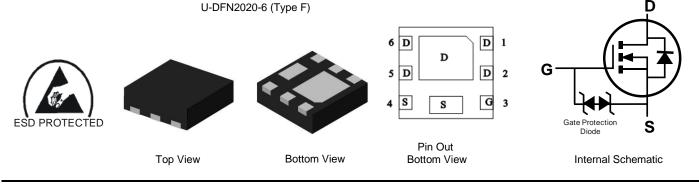
- 0.6mm Profile Ideal for Low Profile Applications .
- PCB Footprint of 4mm²
- Low Gate Threshold Voltage
- Fast Switching Speed
- **ESD** Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)

20V N-CHANNEL ENHANCEMENT MODE MOSFET

- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

- Case: U-DFN2020-6 (Type F)
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish NiPdAu over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @4)
- Weight: 0.0065 grams (Approximate)



Ordering Information (Note 4)

Part Number	Reel Size (inches)	Quantity per Reel
DMN2028UFDF-7	7	3,000
DMN2028UFDF-13	13	10,000

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green"

and Lead-free.

Notes:

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds. 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information

ND Š NC

ND or NC = Product Type Marking Code YM = Date Code Marking Y = Year (ex: C = 2015)

M = Month (ex: 9 = September)

Date Code Key

Eale eeae liej												
Year	201	5	2016		2017	20	18	2019		2020	2	2021
Code	С		D		E	F	-	G		Н		
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D

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Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	20	V		
Gate-Source Voltage		V _{GSS}	±8	V	
	Steady State	T _A = +25°C T _A = +70°C	ID	7.9 6.3	А
Continuous Drain Current (Note 6) $V_{GS} = 4.5V$	t<5s	T _A = +25°C T _A = +70°C	ID	9.4 7.5	A
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%		I _{DM}	40	A	
Continuous Source-Drain Diode Current	Is	2	A		
Avalanche Current (Note 7) L = 0.1mH	IAS	12	A		
Avalanche Energy (Note 7) L = 0.1mH	E _{AS}	8	mJ		

Thermal Characteristics

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Characteristic		Symbol	Value	Unit
Tatal Dawar Dissinction (Nata 5)	T _A = +25°C	D	0.66	W
Total Power Dissipation (Note 5)	T _A = +70°C	PD	0.42	vv
Thermal Registeres, Junction to Ambient (Note 5)	Steady state	Р	186	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<5s	$R_{ hetaJA}$	135	
Total Power Dissipation (Note 6)	T _A = +25°C	P	2.03	W
Total Power Dissipation (Note 6)	$T_A = +70^{\circ}C$	PD	1.31	
Thermal Resistance, Junction to Ambient (Note 6)	Steady state	D	64	°C/W
memai Resistance, Junction to Ambient (Note 6)	t<5s	R _{0JA}	43	
Thermal Resistance, Junction to Case (Note 6)	Steady state	R _{θJC}	18	
Operating and Storage Temperature Range		T _{J.} T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)						
Drain-Source Breakdown Voltage	BV _{DSS}	20		—	V	$V_{GS} = 0V, I_D = 250\mu A$
Zero Gate Voltage Drain Current T _J = +25°C	I _{DSS}	—	—	1	μA	$V_{DS} = 20V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	—	—	±10	μA	$V_{GS} = \pm 8V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)						
Gate Threshold Voltage	V _{GS(TH)}	0.5	_	1.0	V	$V_{DS} = V_{GS}$, $I_D = 250 \mu A$
			15	25		$V_{GS} = 4.5V, I_D = 4A$
Static Drain-Source On-Resistance	Proven		18	29	mΩ	$V_{GS} = 2.5V, I_D = 4A$
Static Drain-Source On-Resistance	R _{DS(ON)}	_	24	39	11152	$V_{GS} = 1.8V, I_D = 4A$
			35	95		$V_{GS} = 1.5V, I_D = 4A$
Forward Transfer Admittance	Y _{fs}	—	18	—	S	$V_{DS} = 5V, I_D = 12A$
Diode Forward Voltage	V _{SD}	—	0.7	1.0	V	$V_{GS} = 0V, I_{S} = 5A$
DYNAMIC CHARACTERISTICS (Note 9)						
Input Capacitance	Ciss	—	907	—		
Output Capacitance	C _{oss}	—	98	—	pF	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz
Reverse Transfer Capacitance	Crss	—	38	—		1 - 1.00012
Gate Resistance	Rg	_	194	—	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge (V _{GS} = 4.5V)	Qg	—	9.8	—		
Total Gate Charge (V _{GS} = 8V)	Qg	_	18	—	nC	Vps = 10V. lp = 6.5A
Gate-Source Charge	Q _{gs}	—	1.5	—	nc	$v_{\rm DS} = 10v, 1_{\rm D} = 6.5 {\rm A}$
Gate-Drain Charge	Q _{gd}	—	1.8	—		
Turn-On Delay Time	t _{D(ON)}	—	56	—		
Turn-On Rise Time	t _R	—	87	—		$V_{DS} = 10V, V_{GS} = 4.5V,$
Turn-Off Delay Time	t _{D(OFF)}	_	632	—	ns	$R_G = 6\Omega$, $R_L = 10\Omega$, $I_D = 1A$
Turn-Off Fall Time	t _F	—	239	—	1	
Reverse Recovery Time	t _{RR}	_	143	_	ns	I _F = 4A, di/dt = 100A/µs
Reverse Recovery Charge	Q _{RR}		136	—	nC	I _F = 4A, di/dt = 100A/µs

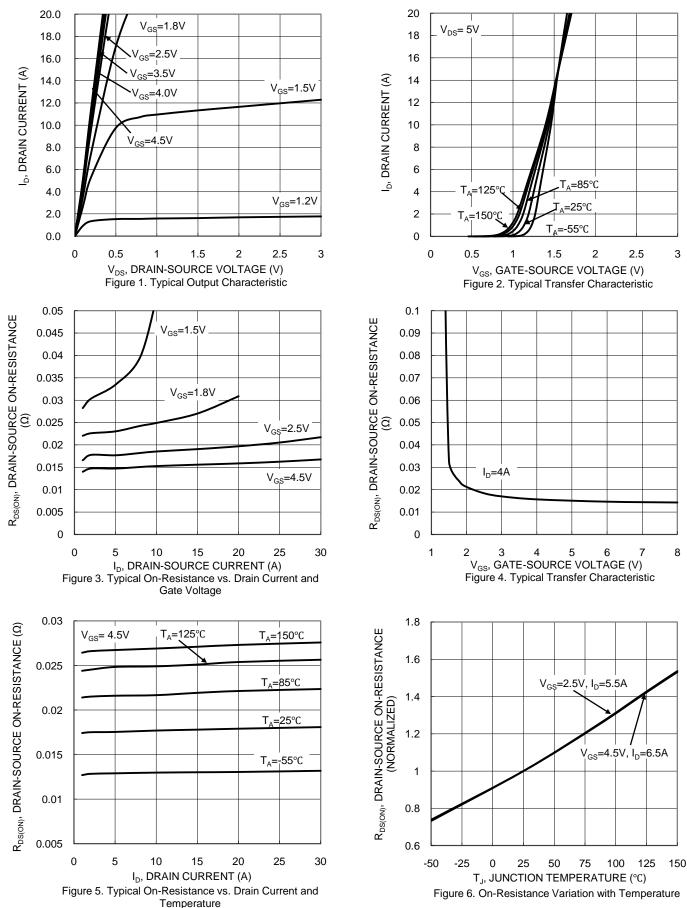
 Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep T_J = +25°C.

Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



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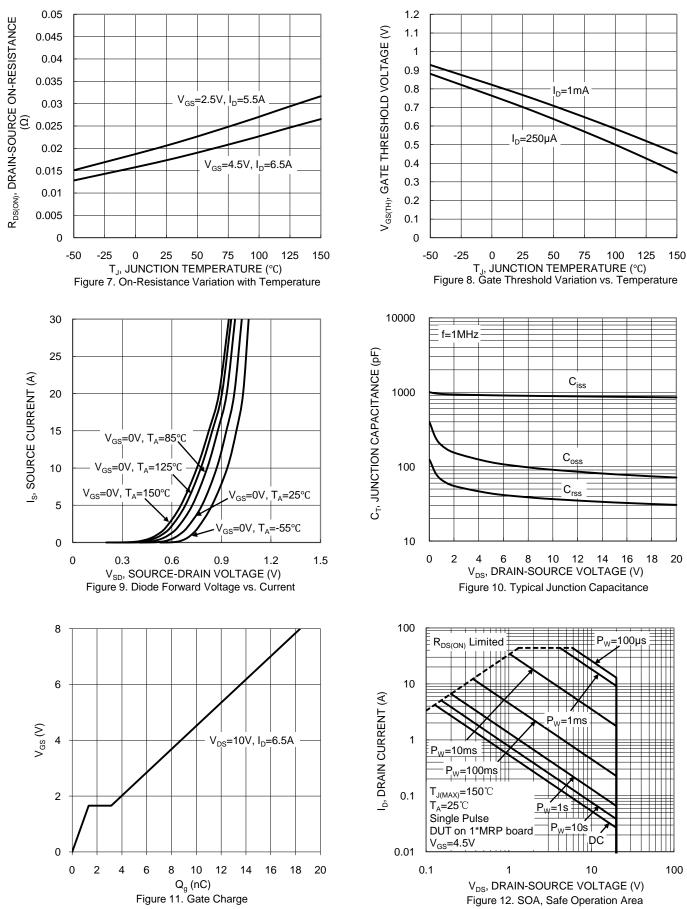


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DMN2028UFDF Datasheet number: DS37937 Rev. 2 - 2 December 2015 © Diodes Incorporated



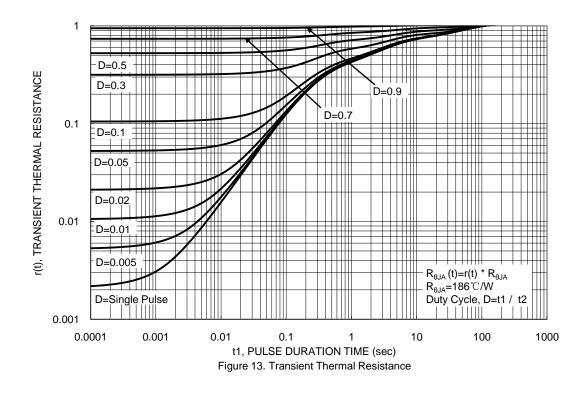
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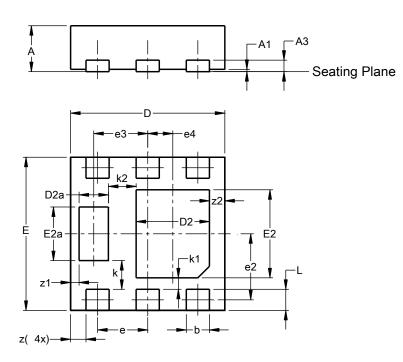




Package Outline Dimensions

Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.

U-DFN2020-6 (Type F)

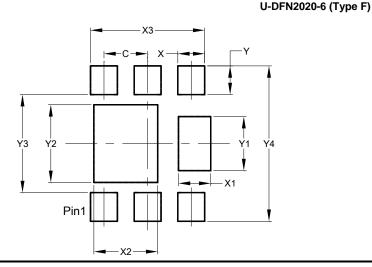


U-DFN2020-6									
(Туре F)									
Dim	Min	Max	Тур						
Α	0.57	0.63	0.60						
A1	0.00	0.05	0.03						
A3	-	0.15							
b	0.25	0.25 0.35 0.30							
D	1.95	1.95 2.05 2.00							
D2	0.85								
D2a	0.33								
ш	1.95	1.95 2.05 2.00							
E2	1.05	1.25	1.15						
E2a	0.65	0.75	0.70						
e	0.65 BSC								
e2	(0.863 BSC							
e3		0.70 BS	С						
e4	().325 BS	SC						
k		0.37 BS	С						
k1		0.15 BS	С						
k2		0.36 BS	С						
L	0.225	0.325	0.275						
z		0.20 BS	С						
z1	().110 BS	SC						
z2		0.20 BSC							
All C	Dimens	ions in	mm						



Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	0.650
Х	0.400
X1	0.480
X2	0.950
X3	1.700
Y	0.425
Y1	0.800
Y2	1.150
Y3	1.450
Y4	2.300

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